



ZXTP25100CZ

#### 100V PNP MEDIUM POWER TRANSISTOR IN SOT89

#### **Features**

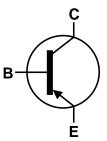
- BV<sub>CEO</sub> > -100V
- $BV_{ECO} > -7V$
- I<sub>C</sub> = -1A Continuous Collector Current
- I<sub>CM</sub> = -3A Peak Collector Current
- $V_{CE(SAT)} < -225mV @ -1A$
- $R_{CE(SAT)} = 155m\Omega$  for a Low Equivalent On-Resistance
- Complementary NPN Type: ZXTN25100DZ
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

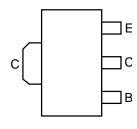
- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.05 grams (Approximate)







Device Symbol



Top View Pin Out

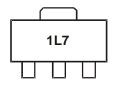
#### **Ordering Information** (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP25100CZTA	AEC-Q101	1L7	7	12	1,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



1L7 = Product Type Marking Code

ZXTP25100CZ 1 of 8 April 2016 Datasheet Number: DS33759 Rev. 2 - 2 © Diodes Incorporated



#### Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	-115	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-100	V
Emitter-Collector Voltage (Reverse Blocking)	V <sub>ECO</sub>	-7	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	I <sub>CM</sub>	-3	Α
Base Current	lΒ	-500	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
	(Note 5)		1.1 8.8		
Power Dissipation	(Note 6)	P <sub>D</sub>	1.8 14.4	W mW/°C	
Linear Derating Factor	(Note 7)		2.4 19.2		
	(Note 8)		4.46 35.7		
	(Note 5)		117		
Thermal Decistores, Junction to Ambient Air	(Note 6)	$R_{ hetaJA}$	68		
Thermal Resistance, Junction to Ambient Air	(Note 7)		51	°C/W	
	(Note 8)		28	1	
Thermal Resistance, Junction to Lead	(Note 9)	$R_{\theta JL}$	7.95		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 10)

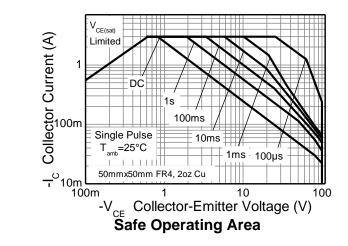
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

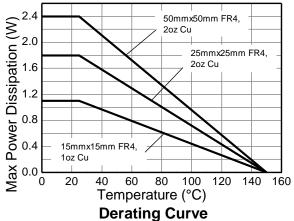
Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 0.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 2oz copper.
- 7. Same as Note 5, except the device is mounted on 50mm x 50mm 2oz copper.
- 8. Same as Note 7, except the device is measured at t<5 seconds.
- 9. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 10. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



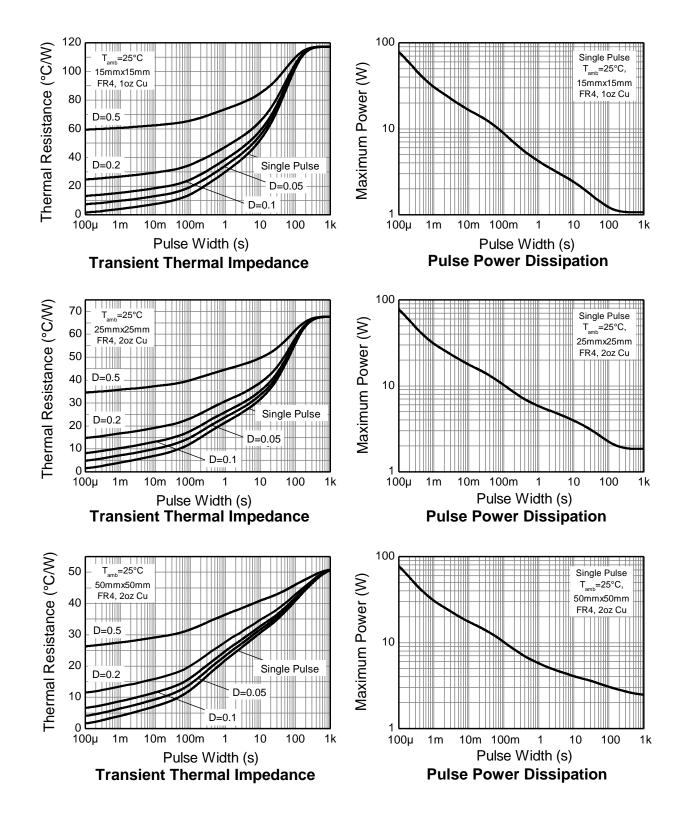
## **Thermal Characteristics and Derating Information**







#### Thermal Characteristics and Derating Information (Continued)





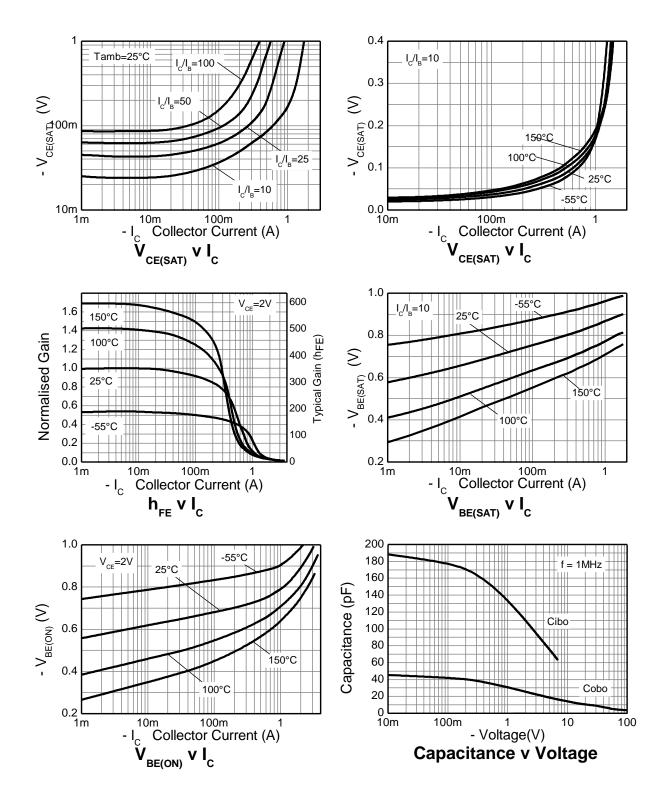
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	-115	-180	_	V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 11)	BV <sub>CEO</sub>	-100	-140	_	V	$I_C = -10mA$
Emitter-Collector Breakdown Voltage (reverse blocking)	BV <sub>ECX</sub>	-7	-8.3	_	V	$I_E$ = -100μA, $R_{BC}$ <1k $\Omega$ or -0.25V > $V_{BC}$ > 0.25V
Emitter-Collector Breakdown Voltage (Reverse Blocking)	BV <sub>ECO</sub>	-7	-8.8	_	V	I <sub>E</sub> = -100μA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.4	_	V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I <sub>CBO</sub>	1	<-1	-50 -0.5	nA μA	V <sub>CB</sub> = -115V V <sub>CB</sub> = -115V, T <sub>A</sub> = +100°C
Collector-Emitter Cutoff Current	I <sub>CEX</sub>	_	_	-100	nA	$V_{CE}$ = -90V, $R_{BE}$ <1k $\Omega$ or -0.25V < $V_{BE}$ < 1V
Emitter Cutoff Current	I <sub>EBO</sub>	_	<1	-50	nA	$V_{EB} = -5.6V$
DC current transfer Static ratio (Note 11)	h <sub>FE</sub>	200 180 110 20	350 320 190 35	500 — — —	_	$I_{C} = -10 \text{mA}, V_{CE} = -2 \text{V}$ $I_{C} = -100 \text{mA}, V_{CE} = -2 \text{V}$ $I_{C} = -500 \text{mA}, V_{CE} = -2 \text{V}$ $I_{C} = -1 \text{A}, V_{CE} = -2 \text{V}$
Collector-Emitter Saturation Voltage (Note 11)	VCE(SAT)	_	-140 -80 -180 -155	-210 -115 -315 -225	mV	$I_C$ = -100mA, $I_B$ = -1mA $I_C$ = -500mA, $I_B$ = -50mA $I_C$ = -500mA, $I_B$ = -20mA $I_C$ = -1A, $I_B$ = -100mA
Base-Emitter Saturation Voltage (Note 11)	V <sub>BE(SAT)</sub>	_	-860	-950	mV	I <sub>C</sub> = -1A, I <sub>B</sub> = -100mA
Base-Emitter Turn-On Voltage (Note 11)	V <sub>BE(ON)</sub>	_	-800	-900	mV	I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V
Transitional Frequency	f⊤	_	180	_	MHz	I <sub>E</sub> = -20mA, V <sub>CE</sub> = -15V f = 100MHz
Input Capacitance	C <sub>IBO</sub>		153	_	pF	$V_{EB} = -0.5V, f = 1MHz,$
Output Capacitance	C <sub>OBO</sub>		14.1	20	pF	V <sub>CB</sub> = -10V, f = 1MHz,
Delay Time	$t_D$	1	15.8	_	ns	
Rise Time	t <sub>R</sub>		41	_	ns	$I_C = -500 \text{mA}, V_{CC} = -10 \text{V},$
Storage Time	ts		411	_	ns	$I_{B1} = -I_{B2} = -50 \text{mA}$
Fall Time	t <sub>F</sub>	_	89	_	ns	

Note: 11. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

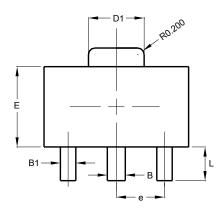


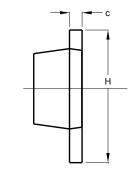


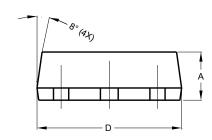
## **Package Outline Dimensions**

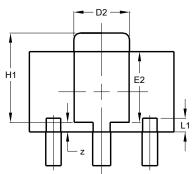
Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT89







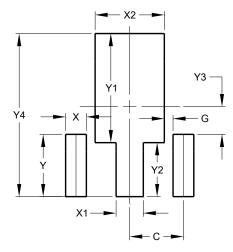


SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	-	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
Z	0.20	0.40	0.30			
All Dimensions in mm						

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT89



Dimensions	Value
Dimensions	(in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Y	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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